Silicon Motion’s Ferri Family
Optimizes Embedded Flash-based Storage for Automotive Use

The In-Vehicle Infotainment (IVI) systems in new car designs today have a huge appetite for data storage capacity – and this appetite is only set to grow. Mapping and navigation, music and entertainment, mirroring of smartphone user interfaces and other IVI applications are occupying a growing memory footprint in cars: forecasts suggest that the user-data storage requirement in high-end vehicles, which was typically around 32GB in 2014, will likely rise to the range of 256-512GB in 2020.

At one time, the car maker’s choice of high-capacity data storage technology was the familiar Hard Disk Drive (HDD), but reliability and lifetime concerns have seen it fall out of favour to be replaced in modern designs by the solid-state drive (SSD) or embedded Multimedia Card (eMMC).

Certainly the solid-state solution for data storage is inherently better suited to the requirements of car makers, which maintain extremely strict processes and qualification criteria for components and modules built into their products in order to maintain high quality and reliability standards. Unlike an HDD, an SSD or eMMC contains no moving parts, it cannot suffer mechanical failure and is not vulnerable to damage from shock or vibration.

Nevertheless, the NAND Flash arrays on which the SSD and eMMC are based have inherent characteristics which can cause data corruption or data loss, if they are not properly managed. On its own, therefore, the replacement of an electro-mechanical system with a solid-state system does not guarantee a long lifetime of reliable performance. This article outlines the failure modes of solid-state data storage systems, and explains technologies and processes being used today to provide tight control of the reliability and lifetime of the latest high-capacity SSDs and eMMCs.

Automotive industry’s preference for MLC NAND
NAND Flash is the basic memory type found today in billions of smartphones, tablets, media players and set-top boxes, and is also the storage medium in SSDs and eMMCs. NAND Flash is available in three main types: Single-Level Cell (SLC), Multi-Level Cell (MLC) and Triple-Level Cell (TLC). The newest version of TLC, 3D TLC, uses a stacked configuration to achieve even higher memory density than TLC. The memory density of MLC Flash is lower than TLC but higher than SLC.

In automotive SSD and eMMC applications, MLC NAND is preferred today because it provides high density and high reliability at a low cost, and with a lower susceptibility to data loss and corruption than TLC NAND. Data storage capacity of up to 64GB is typically available today in MLC NAND-based eMMC products, and up to 512GB in MLC NAND-based SSDs.

The use of MLC NAND Flash does, however, pose some risk to data integrity and retention. What is this risk, and how should automotive users expect the manufacturers of SSDs and eMMCs to manage it?
Assessing whole-life risks of SSD/eMMC products

The risk of failure or data loss inherent in a NAND Flash array can occur in one of three phases of its life:

· Infant failure occurs very soon after a new device is fabricated. Inherent variability in the NAND Flash fabrication process makes the production of weak or bad blocks or cells inevitable.

· During the device’s rated lifetime, there are various potential causes of data loss and corruption, including bit errors in transmission between the host and the NAND Flash array, sudden power-down events, thermal stress affecting data retention, and read disturbance.

· End of life – NAND Flash products have a cycle life rated in terms of Program/Erase (P/E) cycles, and when this number has been exceeded in any given memory cell, the cell may be expected to fail.

The first two categories of failure are highly undesirable in automotive systems. This is why Silicon Motion, in its Ferri range of data storage products, has developed technologies and techniques for minimising or eliminating the risks of failure and data loss during the rated life of the NAND Flash array.

With these technologies, Silicon Motion is able to give users of its AEC-Q100 qualified FerriSSD and Ferri-eMMC products confidence that they will meet the automotive industry’s uncompromising requirements for reliability and long operating lifetime. Features of the Ferri Family products which enhance the data integrity, longevity and performance of SSD boot loaders include:

· 100% screening of every cell, page and block and comprehensive quality control before shipping, resulting in very low defective parts per million (dppm) rates

· End-to-end data protection with NANDXtend ECC technology to extend operating lifetime

· IntelligentScan & DataRefresh, a technology which pre-empts bit loss and prolongs data retention

In addition, Ferri Family products feature NAND Failure Analysis Capabilities. Silicon Motion leverages years in NAND flash memory knowledge to efficiently debug any issue that might occur, and to provide in-depth failure analysis report with corrective action plan.

Screening for infant failures

The weak memory blocks in a die – the blocks which are responsible for infant failures – are most likely to fail at the extremes of its specified operating-temperature range. For the Ferri Solutions products from Silicon Motion, this range is -40°C to +85°C. By performing a high temperature (85°C) burn-in of every cell, page and block in every NAND Flash die, Silicon Motion can therefore screen out all devices that contain bad blocks. It scraps these parts – they are not shipped to customers.

This policy has the effect of lowering the production yield of Ferri Family devices, but this is a price worth paying for the extremely low dppm that Silicon Motion achieves for Ferri Solutions products shipped to automotive customers (see Figure 1).

In Figure 1, the 100% screening of every cell, page and block at the production stage is highlighted. This results in very low defective parts per million (dppm) rates during shipping. After the burn-in process, the remaining parts are designed for robust product life with FerriSSD technology, ensuring no data lost during the product life and extreme low failure rate during usage.
**Avoiding data loss in normal operation**

The proprietary Silicon Motion stress-testing technology, then, screens out infant failures. But even healthy NAND Flash devices are inherently prone to data loss and corruption in normal operation. There are three main ways in which this kind of failure can occur:

- Exposure to sudden power-off events
- Data loss in transmission
- Imperfect data retention under thermal stress

**Handling SPOR correctly**

Automotive systems are subject for various reasons to sudden power-down events, and the vehicle’s system software is not necessarily designed to trigger a proper Power Down command to an SSD or eMMC. If Sudden Power Off and Recovery (SPOR) processes are not implemented, such an event can cause data loss or a storage system crash. In order to eliminate this risk, Ferri Family products include proprietary Silicon Motion firmware in the SSD or eMMC controller which implements a SPOR process, guaranteeing 100% data integrity.

**New stronger forward error correction**

The ability to manage Error Correction Code (ECC) is a normal function of a NAND Flash controller. The purpose of ECC is to correct for bit errors that occur as a stream of data is written to or read from the NAND Flash array. There are various methods for implementing ECC in NAND Flash-based systems, and some methods achieve a higher level of error correction than others.

Automotive manufacturers work to extremely high quality standards, and their aim is – ideally – to achieve a zero defect rate. In response, Silicon Motion has introduced stronger error correction capabilities into the Ferri Solutions products that it offers to the automotive market.

First, it implements end-to-end error correction across the entire data path (see Figure 2). This corrects errors not only in Read/Write operations at the NAND Flash array, but also in the buffer memory (an SRAM or DRAM device). Further verification of the validity of a data transmission is achieved through CRC checksum tests at the NAND Flash array, at the buffer memory and at the interface between the Ferri Family device and the system host processor.

![Inside of a SSD](image-url)
Second, Silicon Motion has extended the scope of its data protection to allow for the elevated bit error rates commonly experienced when a NAND Flash block has undergone many program/erase cycles. Conventional BCH or RS techniques for ECC are capable of 100% data correction at low bit-error rates, but as a NAND Flash array ages the bit error rate rises. Conventional consumer SSDs and MMCs leave uncorrected errors that go beyond the capability of the BCH or RS algorithms. But for automotive applications, the Ferri Family products implement additional error correction, as shown in Figure 3. Low Density Parity Check (LDPC) algorithms are applied to recover corrupted words (1kB blocks). Silicon Motion also implements Page RAID algorithms capable of recovering a complete 16kB page that contains corrupt data. Together, these technologies ensure the integrity of Read/Write operations, free of bit errors, across the entire rated cycle life of the NAND Flash array.

![Fig.3:LDPC and Page RAID error correction schemes for extended ECC operation](image)

**Mitigating effects of thermal stress**

Data retention is a critical performance parameter for automotive manufacturers: it measures the period over which a bit of data will be retained after being written to a cell. This period is strongly temperature-dependent, as the table in Figure 4 shows. This also shows that data retention in the MLC NAND type is markedly shorter than in SLC NAND.

<table>
<thead>
<tr>
<th>Temp</th>
<th>SLC @ max PE</th>
<th>MLC @ max PE</th>
</tr>
</thead>
<tbody>
<tr>
<td>40</td>
<td>75.58 Mo</td>
<td>12 Mo</td>
</tr>
<tr>
<td>55</td>
<td>12 Mo</td>
<td>1.88 Mo</td>
</tr>
<tr>
<td>70</td>
<td>2.14 Mo</td>
<td>0.34 Mo</td>
</tr>
<tr>
<td>85</td>
<td>0.45 Mo</td>
<td>0.07 Mo</td>
</tr>
</tbody>
</table>

![Fig.4:Data retention in NAND Flash is affected by operating temperature, number of Program/Erase (PE) cycles, and NAND type](image)
Technology implemented in Ferri Family products protects against data retention failure by intelligently scanning blocks and cells, and refreshing those which are at risk of data loss. This Intelligent Scan & DataRefresh function draws on data about the bit error rate per block derived from ECC operation: at a user-selectable threshold for the bit error rate, a Data Refresh is performed (see Figure 5). As Figure 4 shows, at elevated operating temperatures the data retention duration shortens dramatically. Silicon Motion’s Intelligent Scan & DataRefresh function automatically increases the frequency of scanning at higher operating temperatures.

Intelligent Scan & DataRefresh can also prevent data loss caused by read disturbance.

Embedded board-level solutions for mass data storage
As this article has shown, the reliability and data integrity of an SSD or eMMC can be greatly enhanced through the application of burn-in, advanced forward error correction and data refresh functions. Silicon Motion meets the uncompromising requirements of the automotive industry in its AEC-Q100 qualified Ferri Family products through:
- 100% screening of every cell, page and block, and comprehensive quality control before shipping, resulting in very low dppm rates
- End-to-end data protection with NANDXtend ECC technology to extend operating lifetime
- IntelligentScan & DataRefresh for enhanced data retention

Ferri Family products available today are:
- FerriSSD, a 20mm x 16mm BGA package in densities up to 256GB
- Ferri-eMMC, available in various compact BGA packages conforming to the JEDEC industrial standards, in densities up to 128GB

Ferri Family storage solutions are particularly well adapted to the needs of the automotive market, providing a combination of long-term reliable operation, data integrity and data retention to ensure that the solid-state memory matches the quality and reliability of any other electronics system in a vehicle.

For more information about Ferri Family, please go to www.siliconmotion.com or send email to ferri@siliconmotion.com

Fig.5: a Data Refresh returns the bit error rate per block to zero

85°C data retention simulation

Based on 1Ynm MLC, @ 1,000 PE

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